

Octal Transparent Latch, 3-State

CD54/74AC/ACT563 - Inverting CD54/74AC/ACT573 - Non-Inverting

Type Features:

- Buffered inputs
- Typical propagation delay: 4.3 ns @ V_{CC} = 5 V, T_A = 25° C, C_L = 50 pF

The RCA-CD54/74AC563 and CD54/74AC573 and the CD54/74ACT563 and CD54/74ACT573 octal transparent 3-state latches use the RCA ADVANCED CMOS technology. The outputs are transparent to the inputs when the Latch Enable (LE) is HIGH. When the Latch Enable (LE) goes LOW, the data is latched. The Output Enable (OE) controls the 3-state outputs. When the Output Enable (OE) is HIGH, the outputs are in the high-impedance state. The latch operation is independent of the state of the Output Enable.

The CD74AC/ACT563 and CD74AC/ACT573 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC/ACT563 and CD54AC/ACT573, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

Family Features:

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST*/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- ± 24-mA output drive current
 - Fanout to 15 FAST* ICs
 - Drives 50-ohm transmission lines

TRUTH TABLE

Output Enable	Latch Enable	Data	AC/ACT563 Output	AC/ACT573 Output
L.	н	н	L	н
L	н	L	Н	L
L	L	1	н ।	L
L	L	h	L	Н
н	X	×	Z	Z

Note

- L = Low voltage level
- H = High voltage level
- 1 = Low voltage level one set-up time prior to the high to low latch enable transition
- h ≈ High voltage level one set-up time prior to the high to low latch enable transition.
- X = Don't Care
- Z ≈ High Impedance State

This data sheet is applicable to the CD74AC563, CD54/74AC573, and CD54/74ACT573. The CD54AC563 and CD54/74ACT563 were not acquired from Harris Semiconductor.

^{*}FAST is a Registered Trademark of Fairchild Semiconductor Corp.

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIW		
	MIN.	MAX.	UNITS
Supply-Voltage Range, V _{Cc} *: (For T _A = Full Package-Temperature Range) AC Types ACT Types	1.5 4.5	5.5 5.5	V
DC Input or Output Voltage, V _I , V _O	0	Vcc	V
Operating Temperature, T _A :	-55	+125	°C
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V(AC Types) at 3.6 V to 5.5 V(AC Types) at 4.5 V to 5.5 V(ACT Types)	0 0	50 20 10	ns/V ns/V

^{*}Unless otherwise specified, all voltages are referenced to ground.

TERMINAL ASSIGNMENT DIAGRAMS



CD54/74AC563, CD54/74ACT563

CD54/74AC573, CD54/74ACT573

STATIC ELECTRICAL CHARACTERISTICS: AC Series

						AMBIEN	TEMPE	RATURE	(T _A) - °(С	Ţ <u></u>
CHARACTERISTICS	S	TEST COM	IDITIONS	V _{cc}	+:	25	-40 to	o +85	-55 to	+125	UNITS
			l _o (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input				1.5	1.2	_	1.2	_	1.2		
Voltage	V _{IH}			3	2.1	_	2.1		2.1		V
				5.5	3.85		3.85	_	3.85]
Low-Level Input				1.5	_	0.3	_	0.3		0.3	
• Voltage	VIL			3		0.9	_	0.9	'	0.9	V
				5.5	_	1.65	_	1.65	<u> </u>	1.65	
High-Level Output			-0.05	1.5	1.4		1.4		1.4	_	
Voltage	V _{OH}	ViH	-0.05	3	2.9	_	2.9	_	2.9	_	
		or	-0.05	4.5	4.4		4.4	_	4.4		1
		VıL	-4	3	2.58	_	2.48	_	2.4	_	V
			-24	4.5	3.94		3.8		3.7	_	1
		(-75	5.5	_		3.85	_	_	<u> </u>	1
		#. * {	-50	5.5		_	_	_	3.85	_	1
Low-Level Output			0.05	1.5	_	0.1		0.1		0.1	
Voltage	V_{OL}	ViH	0.05	3	_	0.1		0.1		0.1	1
		or	0.05	4.5	_	0.1	_	0.1	_	0.1	1
		VıL	12	3	_	0.36	_	0.44	_	0.5	V
		·	24	4.5	_	0.36		0.44	_	0.5	1
•		(75	5.5				1.65	_	_	1
		#, * {	50	5.5	_	_		_		1.65	1
Input Leakage Current	1,	V _{cc} or GND		5.5	_	±0.1	_	±1	_	±1	μΑ
3-State Leakage		ViH									
Current	loz	or									
		Vic									ļ
		Vo=		5.5	_	±0.5	_	±5	_	±10	μΑ
		Vcc									
		or						1			
		GND									
Quiescent Supply Current, MSI	Icc	V _{cc} or GND	0	5.5		8		80		160	μΑ

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

* Test verifies a minimum 50-ohm transmission-line-drive capability at +85° C, 75 ohms at +125° C.

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

						AMBIEN	T TEMP	ERATURE	E (T _A) - °	С	
CHARACTERIST	ice.	TEST CO	NDITIONS	V _{cc}	+	25	-40 1	o +85	-55 to +125		
or introduction			I _o (V) (mA)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	UNITS	
High-Level Input Voltage	V _{IH}			4.5 to 5.5	2	_	2	_	2	-	v
Low-Level Input Voltage	Vil			4.5 to 5.5		0.8	_	0.8	_	0.8	v
High-Level Output		V _{IH}	-0.05	4.5	4.4		4.4	_	4.4	_	
Voltage V _{OH}	Voltage V _{OH}	or V _{IL}	-24	4.5	3.94		3.8	_	3.7	-	V.
		#, * {	-75	5.5	_		3.85	_		_] v .
			-50	5.5					3.85		
Low-Level Output Voltage VoL	V _{IH}	0.05	4.5		0.1	_	0.1	_	0.1		
	VOL	ViL	24	4.5	_	0.36	l —	0.44	_	0.5]
		#, * {	75	5.5		_	_	1.65	_	_	\ \
		<u>"'</u>	50	5.5		_	_	_	_	1.65	1
Input Leakage Current	l _t	V∞ or GND		5.5	_	±0.1	_	±1	_	±1	μΑ
3-State Leakage Current	loz	V _{IH} or									
		V _{IL} V _O = V _{CC}		5.5		±0.5	_	±5	-	±10	μΑ
		or GND			·						
Quiescent Supply Current, MSI	Icc	V _{cc} or GND	0	5.5		8	 .	80	_	160	μΑ
Additional Quiescent Current per Input P TTL Inputs High 1 Unit Load	Supply in ΔI _{cc}	V _{cc} -2.1		4.5 to 5.5	_	2.4	_	2.8		3	, mA

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

ACT INPUT LOADING TABLE

INPUT	UNIT LOAD*					
INPUT	ACT563	ACT573				
ŌĒ	0.87	0.87				
Dn	0.5	0.5				
LĒ	0.8	0.8				

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

PREREQUISITE FOR SWITCHING: AC Series

		. [AMBIENT TEMPERATURE (TA) -°C				
CHARACTERISTICS	SYMBOL	(V)	-40 to +85		-55 to +125		UNITS	
			MIN.	MAX.	MIN.	MAX.		
LE Pulse		1.5	44	_	50	_		
Width	tw	3.3* 5†	4.9 3.5		5.6 4	_	ns	
Setup Time Data to LE	tsu	1.5 3.3 5	2 2 2		2 2 2	_ 	ns	
Hold Time Data to LE	tн	1.5 3.3 5	33 3.7 2.6		38 4.2 3		ns	

*3.3 V: min. is @ 3 V †5 V: min. is @ 4.5 V

SWITCHING CHARACTERISTICS: AC Series; t, t, = 3 ns, C, = 50 pF

			AMBII	ENT TEMPE	RATURE (1	۸) - °C]
CHARACTERISTICS	SYMBOL	V _{cc} (V)	-40 t	o +85	-55 to	+125	UNITS
		(*)	MIN.	MAX.	MIN.	MAX.	1
Propagation Delays: Data to Qn AC563	t _{PLH} t _{PHL}	1.5 3.3* 5†	3.8 2.7	119 13.4 9.5	3.7 2.6	131 14.7 10.5	ns
AC573	tегн teнr	1.5 3.3 5	3.1 2.2	96 10.8 7.7	- 3 2.1	106 11.9 8.5	ns
LE on Qn AC563	t _{PLH} t _{PHL}	1.5 3.3 5	4.3 3.1	136 15.3 10.9	- 4.2 3	150 16.8 12	ns
AC573	tpLH tpHL	1.5 3.3 5	4.3 3.1	136 15.3 10.9	4.2 3	150 16.8 12	ns
Output Enable Times	tezi tezh	1.5 3.3 5	4.1 2.7	119 14.4 9.5	- 4 2.6	131 15.8 10.5	ns
Output Disable Times	t _{PLZ} t _{PHZ}	1.5 3.3 5	3.7 3	131 13.1 10.5	3.6 2.9	144 14.4 11.5	ns
Power Dissipation Capacitance	C _{PO} §	_	63	Тур.	63	Тур.	рF
Min. (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	4 Typ. @ 25°C				٧
Max. (Peak) V _{OL} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Fig. 1	5	1 Typ. @ 25°C			V	
Input Capacitance	Cı			10		10	pF
3-State Output Capacitance	Co	_	<u> </u>	15		15	pF

*3.3 V: min. is @ 3.6 V max. is @ 3 V

†5 V: min. is @ 5.5 V max. is @ 4.5 V

§C_{PO} is used to determine the dynamic power consumption, per latch.

 $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where $f_i = input$ frequency

C_L = output load capacitance

 V_{CC} = supply voltage.

PREREQUISITE FOR SWITCHING: ACT Series

	SYMBOL	V _{cc} (V)	AMBI				
CHARACTERISTICS			-40 to +85		-55 to +125		UNITS
			MIN.	MAX.	MIN.	MAX.	
LE Pulse Width	tw	5†	3.5	_	4	_	ns
Setup Time Data to LE	t _{su}	5	2	_	2	_	ns
Hold Time Data to LE	tн	5	2.6	_	3	_	ns

†5 V: min. is @ 4.5 V

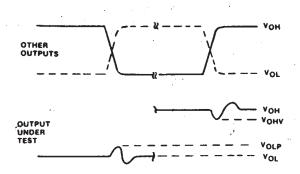
SWITCHING CHARACTERISTICS: ACT Series; t,, t, = 3 ns, C, = 50 pF

		V _{cc} (V)	AMBI	Γ _A) - °C			
CHARACTERISTICS	SYMBOL		-40 to +85		-55 to +125		UNITS
		(*)	MIN.	MAX.	MIN.	MAX.	1
Propagation Delays: Data to Qn 563	t _{PLH}		2.9	10.4	2.9	11.4	
573	1	5†	2.7	9.4	2.6	10.4	ns
LE to Qn 563 573	t _{PLH} t _{PHL}	5	3.2	11.4	3.1	12.5	ns
Output Enable Times	t _{PZL} t _{PZH}	5	3.5	12.3	3.4	13.5	ns
Output Disable Times	t _{PLZ}	5	3.2	11.4	3.1	12.5	ns
Power Dissipation Capacitance	CPO§		63	L Гур.	63	<u>I </u>	pF
Min. (Valley) V _{он} During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	63 Typ. 63 Typ. 4 Typ. @ 25°C				٧
Max. (Peak) Vol. During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Fig. 1	5	1 Typ. @ 25°C				V
Input Capacitance	C _i			10	_	10	ρF
3-State Output Capacitance	Co	_	_	15		15	pF

†5 V: min. is @ 5.5 V max. is @ 4.5 V

§CPD is used to determine the dynamic power consumption, per latch. $P_D = V_{cc}^2 f_c (C_{PD} + C_L) + V_{cc} \Delta I_{cc}$ where $f_c = input$ frequency $C_L = output$ load capacitance $V_{cc} = supply voltage$.

PARAMETER MEASUREMENT INFORMATION

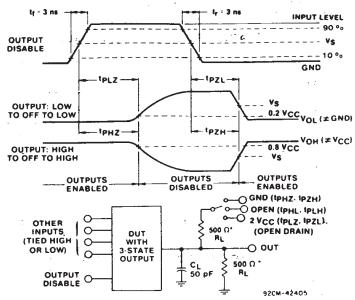


NOTES:

- 1. V_{OHV} AND V_{OLP} ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.
- 2. INPUT PULSES HAVE THE FOLLOWING CHARACTERISTICS:

9205-42406

Fig. 1 - Simultaneous switching transient waveforms.



*FOR AC SERIES ONLY: WHEN $V_{CC} = 1.5~V_{\rm t} R_L = 1~k\Omega$

Fig. 2 - Three-state propagation delay waveforms and test circuit.

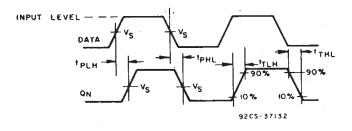


Fig. 3 - Data to Qn output propagation delays.

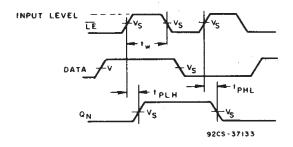


Fig. 4 - Latch enable propagation delays.

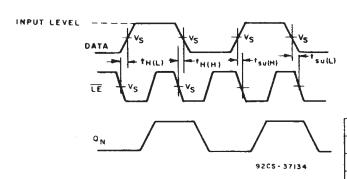


Fig. 5 - Latch enable prerequisite times.

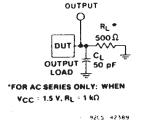


Fig. 6 - Test circuit.

	CD54/74AC	CD54/74ACT
Input Level	V _{cc}	3 V
Input Switching Voltage, Vs	0.5 V _{cc}	1.5 V
Output Switching Voltage, Vs	0.5 V _{cc}	0.5 V _{CC}

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
						(4)	(5)		
CD54AC573F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54AC573F3A
CD54AC573F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54AC573F3A
CD54ACT573F3A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54ACT573F3A
CD54ACT573F3A.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD54ACT573F3A
CD74AC573E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74AC573E
CD74AC573E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74AC573E
CD74AC573M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	AC573M
CD74AC573M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC573M
CD74AC573M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	AC573M
CD74ACT573E	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74ACT573E
CD74ACT573E.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74ACT573E
CD74ACT573M	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-55 to 125	ACT573M
CD74ACT573M96	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT573M
CD74ACT573M96.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	ACT573M

⁽¹⁾ Status: For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54AC573, CD54ACT573, CD74AC573, CD74ACT573:

Catalog: CD74AC573, CD74ACT573

Military: CD54AC573, CD54ACT573

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

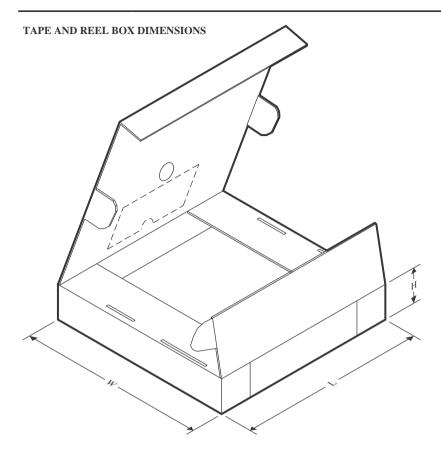


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74AC573M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74ACT573M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1



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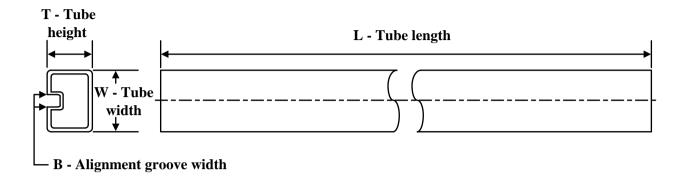
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74AC573M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74ACT573M96	SOIC	DW	20	2000	367.0	367.0	45.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74AC573E	N	PDIP	20	20	506	13.97	11230	4.32
CD74AC573E.A	N	PDIP	20	20	506	13.97	11230	4.32
CD74ACT573E	N	PDIP	20	20	506	13.97	11230	4.32
CD74ACT573E.A	N	PDIP	20	20	506	13.97	11230	4.32

14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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